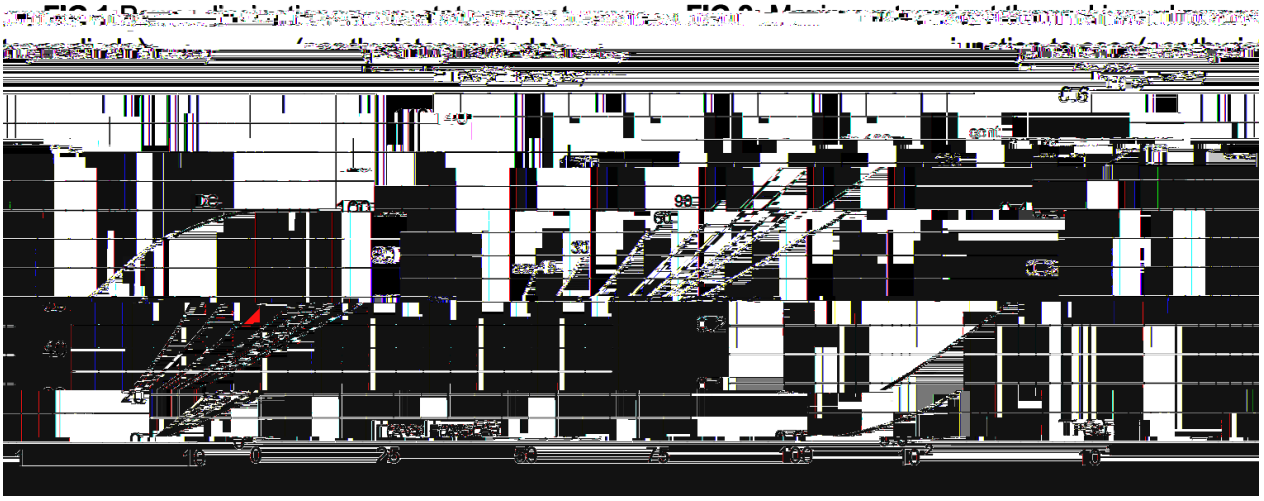
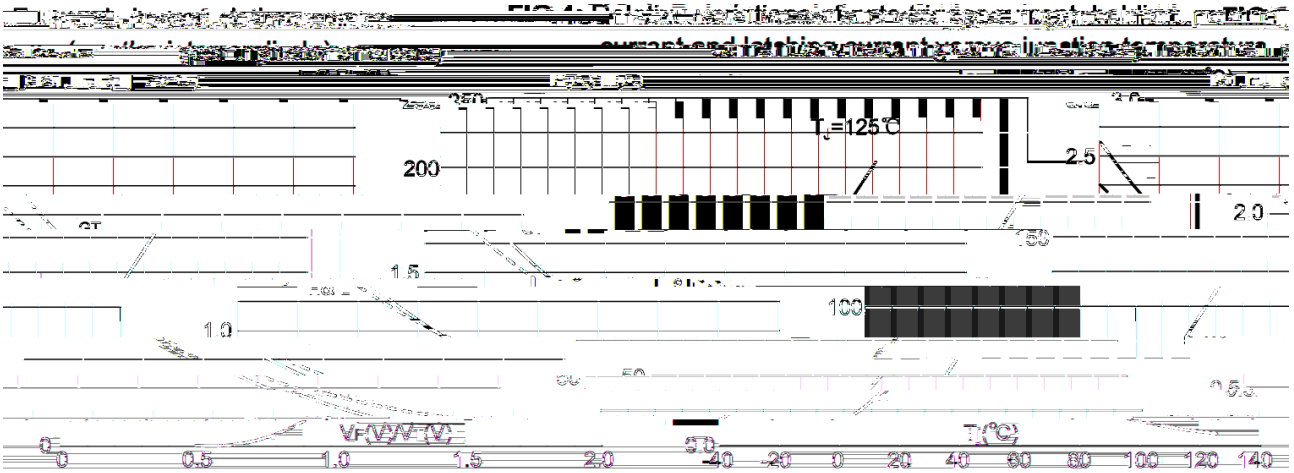
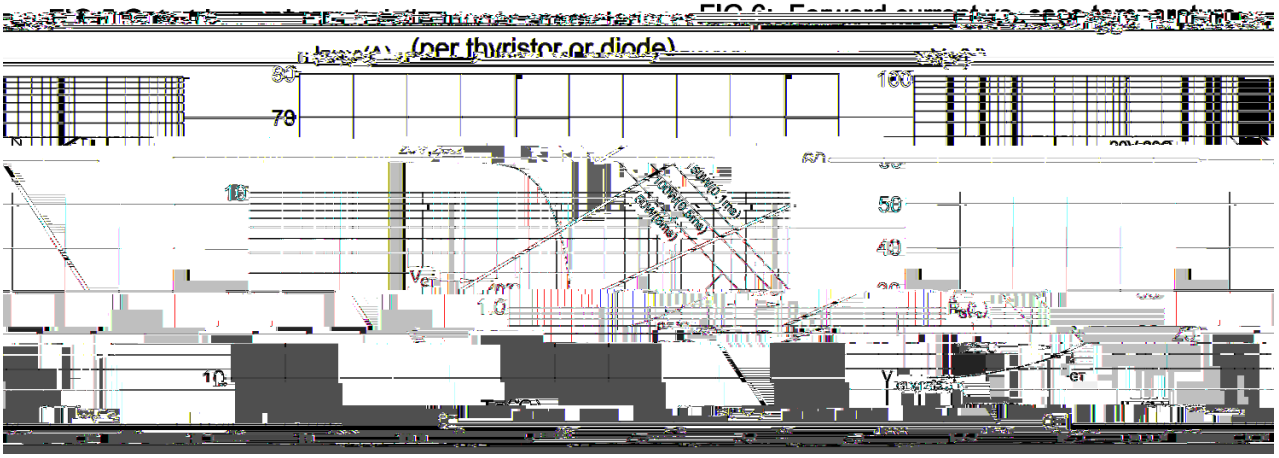
A




T_j=125°C
200
2.5
2.0
1.5
1.0
100
0.5
0
0
0.5
1.0
1.5
2.0
-40
-20
0
20
40
60
80
100
120
140


(per thyristor or diode)
80
70
160
50
40
30
20
10
1.0



